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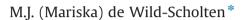


Solar Energy Materials & Solar Cells



Short communication

Energy payback time and carbon footprint of commercial photovoltaic systems



SmartGreenScans, Wagenmakersweg 22, 1873 GH Groet, The Netherlands

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ABSTRACT

Energy payback time and carbon footprint of commercial roof-top photovoltaic systems are calculated based on new 2011 manufacturers' data; and on 2013 equipment manufacturers' estimates of "micro-morph" silicon photovoltaic modules. The energy payback times and carbon footprints are 1.96, 1.24, 1.39, 0.92, 0.68, and 1.02 years and 38.1, 27.2, 34.8, 22.8, 15.8, and 21.4 g CO_2 -eq/kWh for monocrystalline silicon, multicrystalline silicon, amorphous silicon, "micromorph" silicon production with dCICS roof-top photovoltaic systems, respectively, assuming a poly-silicon production with hydropower; ingot-, wafer-, solar cell and module production with UCTE electricity; an irradiation on an optimized-angle of 1700 kWh/(m² × year); excluding installation, operation and maintenance and end-of-life phase. Shifting production of poly-silicon, ingots, wafers, cells and modules to China results in similar energy payback times but increases the carbon footprint by a factor 1.3–2.1, depending on the electricity intensity of manufacturing.

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Solar Energy Material

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1. Introduction

The increase in scale of production of PV modules goes hand in hand with economies of scale of manufacturing and optimized designs. This work shows the latest results for energy payback time and carbon footprint based on new data for commercial scale manufacturing of PV modules and updates of several data sets of ecoinvent 2.2 + [1].

2. Methodology

Life Cycle Assessment (LCA) methodology was used to calculate the cumulative energy demand and global warming potential of PV modules and Balance-of-System components. Energy payback time and carbon footprint were calculated using the IEA PVPS task 12 guidelines [2]. The ecoinvent 2.2 database was used for background data, and calculations were performed with Simapro 7.3.3 software.

Data for PV systems and its components are described in [3] and are based on: (1) manufacturers' data collected by Smart-GreenScans, (2) International Technology Roadmap for Photovoltaics (ITRPV) [4], (3) crystalline silicon solar cell data in [5], (3) market surveys of equipment in Photon International, and

E-mail address: Mariska@smartgreenscans.nl

(4) Estimated data of "micromorph" silicon PV module with Oerlikon Solar THINFAB 120 MWp [6].

The roof-top balance-of-system amounts of a PV system with crystalline silicon modules on a typical Dutch house is described in [7]. The cable diameter for modules with lower module efficiency is smaller but no data are available so far, for thin film modules; therefore the same cabling is assumed here as for crystalline silicon. Inverter sizing values are taken from Stetz [8].

The IEA PVPS task 12 guidelines [2] recommend assuming a performance ratio of 0.75 for roof-top systems. In this study we used a performance ratio of 0.77 which is the average of Belgian and French residential PV systems investigated by Leloux in 2010 [9].

The IEA PVPS task 12 guidelines [2] recommend taking into account a linear power degradation of 20% after 30 years (0.67%/year) for all module technologies. A typical power guarantee on nominal module power is 80% after 25 years [10]. In this study we used system power degradation values of PV systems installed after the year 2000 from a recent literature review by Jordon [11].

To be able to compare the LCA results, the electricity mix to produce solar grade poly-silicon is taken to be hydropower, whereas for the ingots, wafers, cells and modules UCTE electricity mix is assumed. The efficiency of the UCTE electricity grid is 11.4 MJ/kWh (ecoinvent 2.2). The system analyzed is a roof-top PV system with PV modules with optimized-angle. Excluded are installation, operation, maintenance and end-of-life phase. Key parameters are shown in Table 1. High module efficiencies are

^{*} Corresponding author. Tel.: +31 72 5621628.

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Table 1

Key parameters and LCA results for commercial PV systems.

echnology:		mono-Si	mono-Si	multi-Si	multi-Si	a-Si
Product name/description: Scale of production:		average	average	average	average	average 33–45 MWp
*		2011	2011	2011	2011	*
Status:						2008-2011
Electricity mix:		hydro/UCTE	China/China	hydro/UCTE	China/China	UCTE
nstallation type:		roof-top	roof-top	roof-top	roof-top	roof-top
DATA SOURCES						
Data source poly-Si:		ecoinvent 2.2: "Silicon,	ecoinvent 2.2: "Silicon,	ecoinvent 2.2: "Silicon,	ecoinvent 2.2: "Silicon,	not applicable
		solar grade, modified	solar grade, modified	solar grade, modified	solar grade, modified	
		Siemens process, at plant/	Siemens process, at plant/	Siemens process, at plant/	Siemens process, at plant/	
		RER U"	RER U"	RER U"	RER U"	
Data source ingots:		various	various	various	various	not applicable
Data source wafers:		various	various	various	various	not applicable
Data source solar cells:		various	various	various	various	not applicable
Data source modules:		various	various	various	various	2: Germany, T-Sol
Data source modules.		various	Various	various	Various	(Spain)
		Cabletter FreeOF/FreeC	Sablattan Fac05/Fac6	Cabletter FacOF/FacC	Sablattan Fac05/Fac6	Inventux fiX
Data source mounting:		Schletter Eco05/EcoG	Schletter Eco05/EcoG	Schletter Eco05/EcoG	Schletter Eco05/EcoG	
Data source inverter:		ecoinvent 2.2	ecoinvent 2.2	ecoinvent 2.2	ecoinvent 2.2	ecoinvent 2.2
Background data:	ecoinvent	ecoinvent 2.2	ecoinvent 2.2	ecoinvent 2.2	ecoinvent 2.2	ecoinvent 2.2
EY PARAMETERS						
POLY-SILICON						
echnology:		solar grade Siemens	solar grade Siemens	solar grade Siemens	solar grade Siemens	not applicable
Feedstock	kg virgin/	1.192	1.192	0.625	0.625	not applicable
	m ² module					- •
NGOTS & WAFERS	"as grown"					
	crystal/ingot					
Vafer size:	erystal/ing0t	156 mm × 156 mm	156 mm × 156 mm	156 mm × 156 mm	156 mm × 156 mm	not applicable
Vafer size: Vafer thickness:						* *
	1	180–200 μm	180–200 μm	180–200 μm	180–200 μm	not applicable
/irgin Si charging of	kg virgin/kg	0.781	0.781	0.700	0.700	not applicable
crucible:	crystal					
ngot/wafer	kg crystal/	0.0385	0.0385	0.0224	0.0224	not applicable
	wafer					
	wafers/m ²	39.66	39.66	39.85	39.85	not applicable
	module					
AB electricity	kWh/kg	68.18	68.18	15.49	15.49	not applicable
consumption:	crystal					
AB electricity	kWh/wafer	0.62	0.62	0.51	0.51	not applicable
•	K v v ii/ v aici	0.02	0.02	0.51	0.51	not applicable
consumption:						
OLAR CELLS		450 450	450 450	450 450	450 450	
Solar cell size:		156 mm × 156 mm	$156 \text{ mm} \times 156 \text{ mm}$	156 mm imes 156 mm	$156 \text{ mm} \times 156 \text{ mm}$	not applicable
Wafers/cell	wafers/cell		1.030	1.035	1.035	not applicable
Cells/module:	cells/m ²	38.50	38.50	38.50	38.50	not applicable
	module					
AB electricity	kWh/cell	0.35	0.35	0.35	0.35	not applicable
consumption:						
IODULES						
Cells in one module:		6×10	6×10	6×10	6×10	not applicable
ells/module:	cells/	61.5	61.5	61.5	61.5	not applicable
ciis/illouule.	module	01.5	01.3	01.3	01.3	not applicable
lace longth		096	0.96	086	086	2200
Glass length:	mm	986	986	986	986	2200
lass width:	mm	1620	1620	1620	1620	2600
lass area:	m ²	1.6	1.6	1.6	1.6	5.72
Iodule	modules/	0.626	0.626	0.626	0.626	0.175
	m ²					
Iodule weight:	kg	20	20	20	20	118
Iodule weight/area:	kg/m ²	12.5	12.5	12.5	12.5	21
Iodule efficiency:	к <u>ы</u> ш %	14.8%	14.8%	14.1%	14.1%	7.0%
/odule power/area:	Wp/m ²	148	148	141	141	70
Iodule area/power:	m ² /kWp		6.76	7.09	7.09	14.29
/1	ш /күүр	6.76				
Aodule composition:		glass-EVA-backsheet	glass-EVA-backsheet	glass-EVA-backsheet	glass-EVA-backsheet	glass-PVB-glass
lass:		single	single	single	single	double
lass thickness:	mm	3.2	3.2	3.2	3.2	3.2
lass density:	kg/m ³	2500	2500	2500	2500	2500
ncapsulation material:		ethylvinylacetate (EVA)	ethylvinylacetate (EVA)	ethylvinylacetate (EVA)	ethylvinylacetate (EVA)	polyvinylbutyral
						(PVB)
Encapsulation thickness:	μm	450	450	450	450	760
incapsulation density:	kg/m ³	955	955	955	955	1079
Encapsulation cutting	0	1%	1%	1%	1%	6%
loss:						
acksheet thickness:		330	330	330	330	none
ackSHEEL HHCKHESS:	μm		330 6%	330 6%	330 6%	none
				D/6	D/6	
acksheet cutting loss:		6%				
	kg/m ²	aluminum 2.13	aluminum 2.13	aluminum 2.13	aluminum 2.13	none 0

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